1 Solvent engineering of MAPbI₃ perovskite thick film for direct

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X-ray detector

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Figure.S3 The cross section SEM images of the 100μm perovskite films
 (experimental sample).



Figure. S4. EDS Analysis for different areas on the surface of perovskite films in the
 Control Group.



Figure.S5 The perovskite film of experimental group was dissolved in DMSO solvent
 for NMR analysis





Figure. S7 (e) The X-ray response profiles of the control and experimental detectors
 with a varying dose rate ranging from 2.25 mGy_{air}s⁻¹ to 0.225 mGy_{air}s⁻¹.





Device Structure	E _{ph} (keV)	<i>E</i> (V mm ⁻¹)	$S (\mu CGy_{air}^{-1} cm^{-2})$	LoD (nGy _{air} s ⁻¹)	Ref.
Au//CsPbBr ₃ /Au	50	20	918		60
Au//RbCsPbBr ₃ /Au	50	20	8097		60
Au/(BA) ₂ EA ₂ Pb ₃ Br ₁₀ /Au	70	5	6.8×10 ³	5500	61
Au/Cs ₂ AgBiBr ₆ /Au	50	50	1974	45.7	62
Au/PEA-Cs2AgBiBr6/Au	50	23	288.8		62
Au/(BA) ₂ CsA _g BiBr ₇ /Au	70	5	4.2		63
Ag/(H2MDAP)BiI5/Ag	70	5	1		64
PEN/NiO _x / Cs _{0.1} FA _{0.75} MA _{0.15} PbBr _{0.5} I _{2.5} /PCBM/ BCP/Au	70	27	33.5	12000	38
ITO/Pt/Polymer/CsPbBr ₃ / W	70	45.5	1.2×10 ⁴		65
ITO/TiO ₂ /Cs ₂ TeI ₆ /PTAA/Au	60	50	0.24		66
FTO/MAPbI ₃ /C	60	15	7304	154	This work